



DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| BV _{DSS} | R _{DS(ON)} max | I _D max T _A = +25°C | |
|-------------------|-----------------------------|--|--|
| 30V | 3Ω @ $V_{GS} = 4.5V$ | 350mA | |
| | $7\Omega @ V_{GS} = 2.5V$ | SSUIIA | |

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- Power Management Functions
- DC-DC Converters
- Backlighting

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Mechanical Data

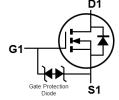
- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)

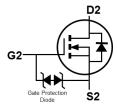


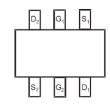


Top View

SOT563







Internal Schematic

Top View Pin Out

Ordering Information (Note 4)

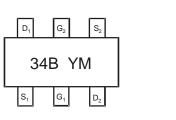
| Part Number | Marking | Reel Size (inches) | Tape Width (mm) | Quantity Per Reel |
|---------------|---------|--------------------|-----------------|-------------------|
| DMN33D9LV-7 | 34B | 7 | 8 | 3,000 |
| DMN33D9LV-7A | 34B | 7 | 8 | 3,000 |
| DMN33D9LV-13 | 34B | 13 | 8 | 10,000 |
| DMN33D9LV-13A | 34B | 13 | 8 | 10,000 |

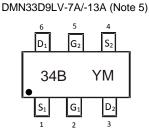
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information







34B = Product Type Marking Code YM = Date Code Marking Y = Year (ex: G = 2019)

M = Month (ex: 9 = September)

Date Code Key

| Year | 201 | 9 | 2020 | | 2021 | 20 | 22 | 2023 | | 2024 | 2 | 2025 |
|-------|-----|-----|------|-----|------|-----|-----|------|-----|------|-----|------|
| Code | G | | Н | | I | | J | K | | L | | M |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |

Note: 5. Part number with suffix 7A and 13A designates devices marked with a Pin 1 indicator. There is no other difference between both devices.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|--|------------------|----------------|------------|----|
| Drain-Source Voltage | V _{DSS} | 30 | V | |
| Gate-Source Voltage | V_{GSS} | ±20 | V | |
| Continuous Drain Current (Note 6) $V_{GS} = 4.5V$ Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$ | | I _D | 350 200 | mA |
| Maximum Continuous Body Diode Forward Current | Is | 0.5 | Α | |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1% | I _{DM} | 0.8 | Α | |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|--|-----------------------------------|----------------|------|---|--|
| Total Dayyar Dissination (Note 6) | T _A = +25°C | Б | 0.43 | W | |
| Total Power Dissipation (Note 6) | T _A = +70°C | P _D | 0.20 | | |
| Thermal Resistance, Junction to Ambient (Note 6) | R _{θJA} | 288 | °C/W | | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C | | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

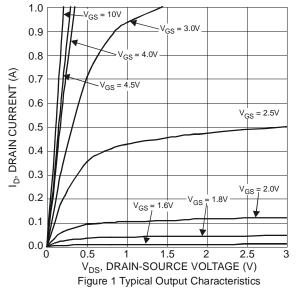
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|---------------------|-----|------|-----|------|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | _ | _ | V | $V_{GS} = 0V$, $I_D = 1mA$ |
| Zero Gate Voltage Drain Current @T _C = +25°C | I _{DSS} | _ | _ | 1 | μA | $V_{DS} = 30V, V_{GS} = 0V$ |
| Gate-Source Leakage | I _{GSS} | _ | _ | ±10 | μA | $V_{GS} = \pm 16V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 0.8 | 1 | 1.4 | V | $V_{DS} = 3V, I_{D} = 100\mu A$ |
| | | _ | 0.2 | 2.4 | | $V_{GS} = 10V, I_D = 250mA$ |
| Static Drain-Source On-Resistance | | _ | 0.3 | 3.0 | Ω | $V_{GS} = 4.5V, I_D = 250mA$ |
| Static Dialii-Source On-Resistance | R _{DS(ON)} | _ | 0.3 | 5.0 | Ω | $V_{GS} = 4.0V, I_D = 10mA$ |
| | | _ | 0.7 | 7.0 | | $V_{GS} = 2.5V, I_D = 10mA$ |
| Diode Forward Voltage | | _ | 0.8 | 1.2 | V | V _{GS} = 0V, I _S = 115mA |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | | _ | 48 | _ | pF | |
| Output Capacitance | | _ | 11 | _ | pF | $V_{DS} = 5V, V_{GS} = 0V,$ f = 1.0MHz |
| Reverse Transfer Capacitance | C _{rss} | _ | 8 | _ | pF | 1 - 1.00/12 |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 0.55 | _ | nC | |
| Total Gate Charge (V _{GS} = 10V) | Qg | _ | 1.23 | _ | nC | $V_{GS} = 10V, V_{DS} = 10V,$ |
| Gate-Source Charge | Q _{gs} | _ | 0.14 | _ | nC | $I_D = 250 \text{mA}$ |
| Gate-Drain Charge | Q _{gd} | _ | 0.14 | _ | nC |] |
| Turn-On Delay Time | | _ | 2.9 | _ | ns | |
| Turn-On Rise Time | | _ | 2.6 | _ | ns | $V_{DD} = 30V, V_{GS} = 10V,$ |
| Turn-Off Delay Time | | _ | 18.2 | _ | ns | $R_G = 25\Omega$, $I_D = 200mA$ |
| Turn-Off Fall Time | t _F | _ | 13.6 | | ns | |

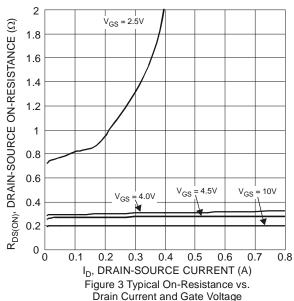
Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

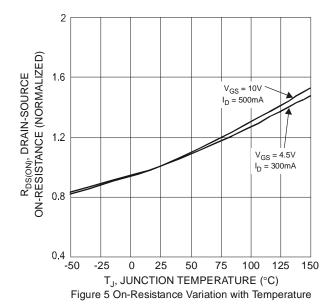
^{7.} Short duration pulse test used to minimize self-heating effect.

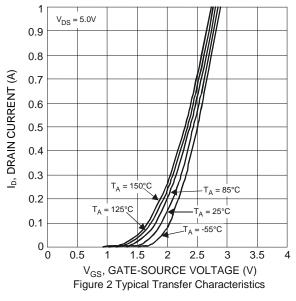
^{8.} Guaranteed by design. Not subject to product testing.

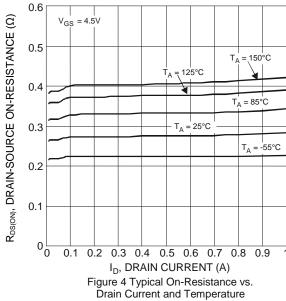












0.5 $R_{DS(ON)}$, DRAIN-SOURCE ON-RESISTANCE (Ω) V_{GS} = 4.5V 0.4 I_D = 300mA 0.3 V_{GS} = 10V 0.2 0.1 -50 -25 25 50 75 100 125 T_J, JUNCTION TEMPERATURE (°C)

Figure 6 On-Resistance Variation with Temperature



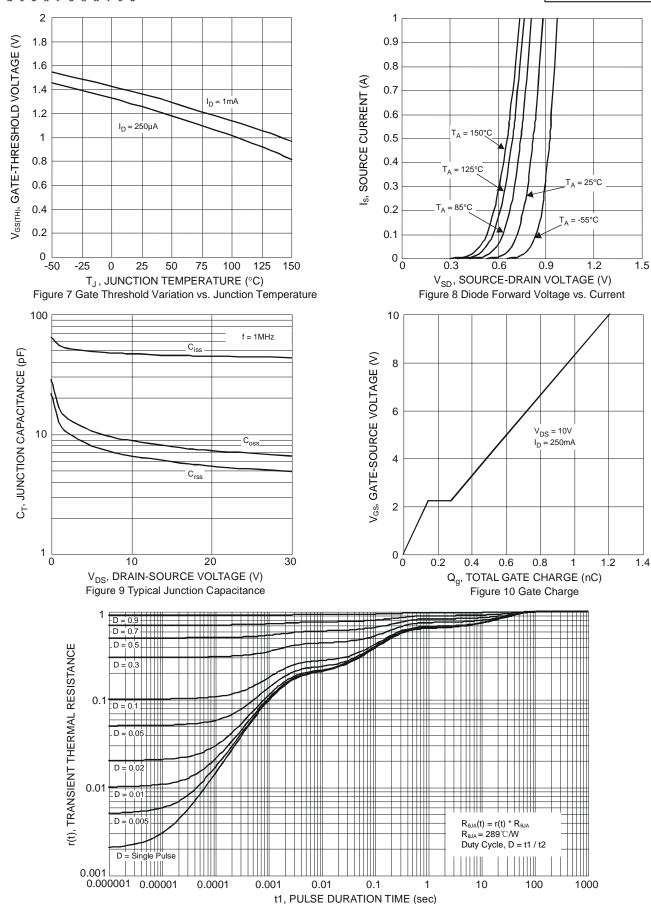


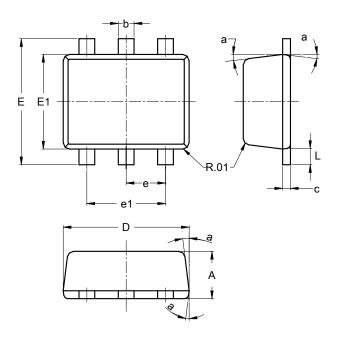
Figure 11 Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563

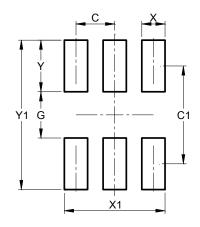


| SOT563 | | | | | | | |
|----------------------|------|------|------|--|--|--|--|
| Dim | Min | Max | Тур | | | | |
| Α | 0.55 | 0.60 | 0.60 | | | | |
| b | 0.15 | 0.30 | 0.20 | | | | |
| С | 0.10 | 0.18 | 0.11 | | | | |
| D | 1.50 | 1.70 | 1.60 | | | | |
| Е | 1.55 | 1.70 | 1.60 | | | | |
| E1 | 1.10 | 1.25 | 1.20 | | | | |
| е | | | 0.50 | | | | |
| e1 | 0.90 | 1.10 | 1.00 | | | | |
| L | 0.10 | 0.30 | 0.20 | | | | |
| а | 8° | 9° | 7° | | | | |
| All Dimensions in mm | | | | | | | |

Suggested Pad Layout

 $\label{please} Please see \ http://www.diodes.com/package-outlines.html \ for the latest version.$

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| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.500 |
| C1 | 1.270 |
| G | 0.600 |
| Х | 0.300 |
| X1 | 1.300 |
| Υ | 0.670 |
| Y1 | 1.940 |



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